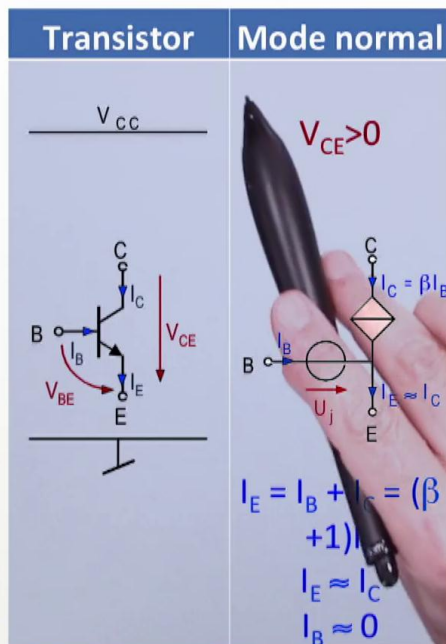


Schémas équivalents grands signaux (analogique)



Electronique II

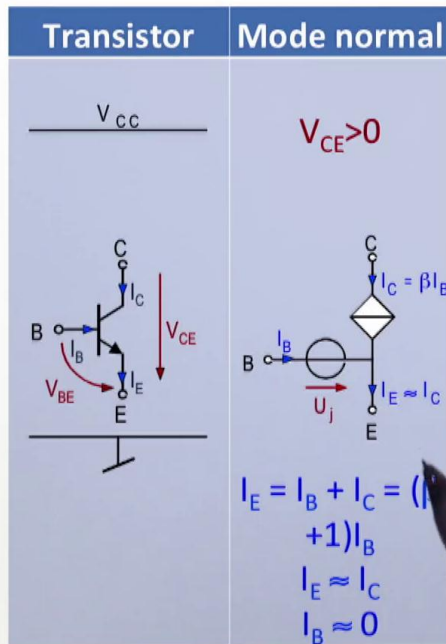
Well to end this introductory course on transistors, let's take a look on equivalent diagrams where we will propose a diagram that represents the transistor according to each mode of use of this transistor. So we have seen that there are three modes: blocked, the blocked transistor, if we simply remove it from the circuit, it will disappear, we will see how we replace the transistor when it is in normal mode and we will end by replacing a transistor with an equivalent diagram when it is saturated. These are equivalent diagrams called large-signal equivalent diagrams that will be useful especially for a transistor when it is used in the so-called "Analog" circuit. So that's the transistor symbol, I think now you understand, there is a junction voltage in the base-transmitter, there are three currents that fall within the three pins of this transistor so that the Vce voltage, we will make a focus on the value of Vce. Because as we have seen, the normal mode, is really when the transistor is in a world where it conducts, that is to say, we have the base-transmitter voltage which is a voltage of the order of magnitude of the junction voltage and the voltage between collector-transmitter is strictly positive.

Notes

Summary



Schémas équivalents grands signaux (analogique)



Electronique II

If we were able to verify that the transistor conducts and that this voltage stays positive at this moment, it is possible to remove this symbol and replace it with an equivalent diagram which is the following. We replace the voltage between the base and emitter by a voltage, or a source of voltage, called U_j , it is an approximation. And now we have the famous transistor effect, that is to say, the famous transistor effect, the transistor behaves as a current source where the current flowing in the collector, which is drawn into the collector, will go out through the emitter, it is proportional to $\beta \times I_B$, which will draw a small I_B current in the base that would be multiplied by β and this is the diagram we might simply... if someone tells me, your transistor conducts and you verified that the collector-emitter voltage is positive, you remove this pattern and then you replace with this instead. And I just repeat to say, when a transistor with low power, in normal mode, which draws a current I_C , we can simply do this approximation that the current $I_C + I_B$ that will give the current I_E , here you write like that, and you replace the current I_C by $\beta \times I_B$ and you bring to light I_B , you will find that it is $\beta + 1$, we can neglect the 1 relative to β which is usually very, very big.

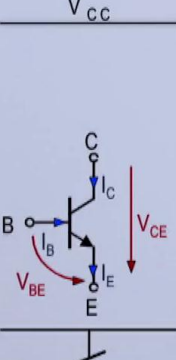
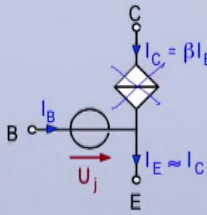

Notes

Summary



1m 19s

Schémas équivalents grands signaux (analogique)

Transistor	Mode normal	Saturation
	$V_{CE} > 0$  $I_E = I_B + I_C = (\beta + 1)I_B$ $I_E \approx I_C$ $I_B \approx 0$	$V_{CE} = V_{CEsat} \approx 0$  $I_{Esat} = I_{Bsat} + I_{Csat}$ $I_{Bsat} > I_{Csat}/\beta$

Electronique II

So we can always say that I_e approximately equals I_c , it is as if we're cancelling the base current, this is what we're saying, this current is almost negligible, so it's approximated by one current approximately equal to 0. That is the normal mode. It focuses on V_{ce} . We will now focus on V_{ce} again, but this time, when V_{ce} is equal to 0. When your transistor is placed in a circuit, we will see just now how we get to saturate a transistor, you apply a collector-transmitter voltage, I mean, you apply because it's the user in his circuit that brings the transistor to saturate and the voltage between the collector-transmitter is equal to 0, that is to say the current source, it will disappear and the transistor will become a real short-circuit as a collector-transmitter and there, there is no longer the transistor effect that we are interested in in the analog circuit, that is when the transistor operates as a current source. And you will end up with a short-circuit between the collector and transmitter, there is no longer the current source effect, so we can not say $I_c = \beta \times I_b$, you are dependent on a diagram. And this diagram we have the transistor conducting, therefore, the junction voltage remains the same.

Notes

Summary



2m 54s

Schémas équivalents grands signaux (analogique)

Transistor	Mode normal	Saturation
	$V_{CE} > 0$ $I_E = I_B + I_C = (\beta + 1)I_B$ $I_E \approx I_C$ $I_B \approx 0$	$V_{CE} = V_{CEsat} \approx 0$ $I_{Esat} = I_{Bsat} + I_{Csat}$ $I_{Bsat} > I_{Csat}/\beta$

Electronique II

The collector-transmitter is a short-circuit, it is replaced in this model by a short circuit, so if you check if $V_{ce} = 0$, you remove your transistor, you replace your transistor by this diagram you see here. And then you end up with a link that will tell you clearly, as here, I_e is the sum of $I_c + I_b$, the two currents enter by the two pins, exit through the transmitter, besides the arrow here indicates the current leaving the transistor and you see it here, but the fundamental difference is that you can not write this relationship. So you are to say it is I_c , we add SAT. We're out of power source, there is a current that may be proportional to a saturation current that we'll see how we calculate it later, but then the more critical is I_{BSAT} . As the relationship has disappeared here, so we can not say that this I_{BSAT} is linked to I_c . And I_c is a constant current, or a current controlled through a power source, you can increase I_{BSAT} , remember that here you have a junction that... a diode. And this diode, the more you increase the base transmitter, the more the base current will increase and we talk of I_{BSAT} . So you will end up with an I_{ESAT} that will be proportional to I_{BSAT} that, it can increase.

Notes

Summary



4m 17s

Schémas équivalents grands signaux (analogique)

Transistor	Mode normal	Saturation
	$V_{CE} > 0$ $I_E = I_B + I_C = (\beta + 1)I_B$ $I_E \approx I_C$ $I_B \approx 0$	$V_{CE} = V_{CEsat} \approx 0$ $I_{Esat} = I_{Bsat} + I_{Csat}$ $I_{Bsat} > I_{Csat} / \beta$

Electronique II

So that current can increase, another current I_{CsAT} will add itself, this current, we will see that it will be quite limited often by a resistor, so you will have a current that is no longer proportional to I_{CsAT} . And you must be very careful, if by chance you continue to increase this current, you may damage the base-transmitter junction, because you're going to apply to it a current which increases with voltage that remains on an exponential curve of the order of U_j , so the dissipated power in the junction will be of the order of U multiplied by I_{BsAT} , but if I_{BsAT} increases, the power increases and you can click the base-transmitter junction, which often happens when we increase, or go into saturation, and the base transmitter voltage wraps up, or increases. What I just explain here is absolutely valid for a PNP transistor, that is why we do not spend time showing the PNP and NPN, because if I take the same thing and I now apply it to a PNP transistor, I find myself with a transistor, I take the symbol, instead of talking of V_{be} as junction voltage, given that the current enters the transmitter and it exits through the base and leaves through the collector, this is the opposite direction of what you see here, well I speak of a V_{eb} voltage.

Notes

Summary



5m 39s

Schémas équivalents grands signaux (analogique)

Transistor	Mode normal	Saturation	Transistor	Mode normal	Saturation
	$V_{CE} > 0$ $I_E = I_B + I_C = (\beta + 1)I_B$ $I_E \approx I_C$ $I_B \approx 0$	$V_{CE} = V_{CEsat} \approx 0$ $I_{Esat} = I_{Bsat} + I_{Csat}$ $I_{Bsat} > I_{Csat}/\beta$		$V_{EC} > 0$ $I_E = I_B + I_C = (\beta + 1)I_B$ $I_E \approx I_C$ $I_B \approx 0$	$V_{EC} = V_{ECsat} \approx 0$ $I_{Esat} = I_{Bsat} + I_{Csat}$ $I_{Bsat} > I_{Csat}/\beta$

I have to continue after, when I talk about normal mode, it's the same condition, but instead of saying V_{ce} must be positive, this time I must say V_{ec} must be positive. And saturation is the same, because here it is equality with 0, then I reverse the direction of arrows in this transistor, which always leads me to exactly the same rules that I apply. As well here and there you find the same laws, you invert the direction of the vectors base-transmitter, transmitter-base and as for the current direction, and the same for output currents therefore the current of the collector-transmitter and voltage between transmitter and collector. There you go. So we will not talk all the time of duality between the two transistors knowing that this transistor is just a transistor whose laws are the same, but simply the directions of voltage and current are different.

Notes

Summary



Transistors	Blocage	Saturation

Electronique II

The bipolar transistor could be used also in logic circuits. Here, we will talk of the transistor in the blocked state and the saturated state. We have seen that saturation can happen to this transistor and it behaves with a short-circuit, rather there is a voltage between the collector-transmitter equal to 0. So it's like a closed switch. It is said that there is a short-circuit between collector and transmitter, it is equivalent to say that the collector-transmitter voltage is equal to 0 and when one locks the transistor, the transistor is simply where you can remove it, if the V_{be} voltage is lower than a voltage junction, your transistor is completely useless. You can remove it from your system, so it is symbolized by an open switch. So then, as we talked about NPN transistor, we can also talk of the PNP transistor. And we end up with the same thing we had presented just before, instead of saying V_{be} , we say V_{eb} and as for the v_{ec} voltage instead of saying v_{ce} but the modes of operation do not change. We block a transistor by applying a voltage less than J , we saturate it on the condition that its output voltage, we circulate a current in a way that the collector-transmitter voltage drop stretches towards 0 and the transistor behaves like a closed circuit.

Notes

Summary



8m 05s

Transistors	Blocage	Saturation

Electronique II

And it allows me to use the bipolar transistor in digital applications. So we may have logic gates, besides the bipolar transistors were the sources of the TLT gates transistor logic transistor, before the MOS transistor came to replace it to make logic circuits that are much more efficient. Why ? Because in this case, there is a current base and in the MOS transistor, there is no base current, therefore the control voltage is sufficient to close, or open, an MOS transistor. However here, when closing a transistor, so when we stand here, it continues to draw current as we had seen before. And that is a current that is wasted. It serves no purpose, there is a power loss in keeping the transistor closed.

Notes

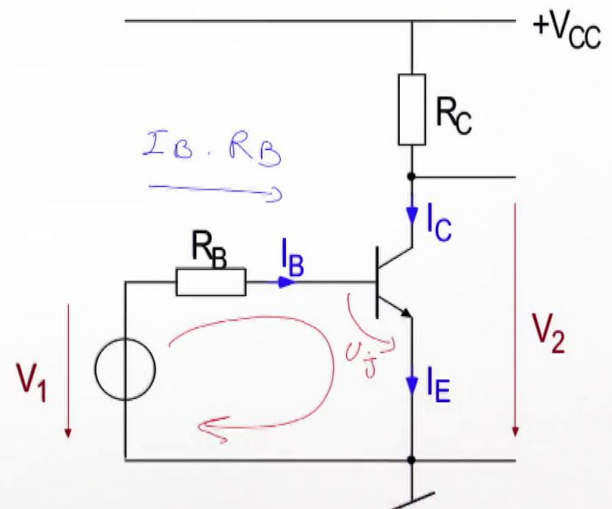
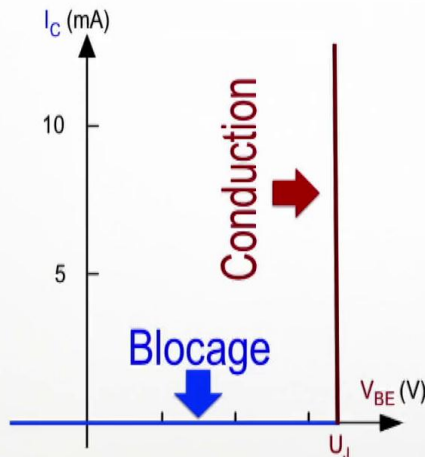
Summary



9m 25s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Blocage du transistor ($V_{BE} < U_J$):



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

To end this week's classes, I would like us to look at an example. Through this example, you'll see that we will master the three modes of transistor uses and show that a transistor, in a diagram, may be blocked in normal and saturated mode. And all this is related to what we put as resistance. For example in this diagram, I have put a resistor in the collector and I put a resistor in the base. The transistor, when it is used in the so-called large signal model, we had this approximation here. We said, when we want to mention the exponential law of a transistor, it could be approximated by blocking, or conduction. So if you take the mesh that is here so this mesh here, this one here, you'll see that the voltage V_1 is equal to the voltage which is there, which is $I_B \times R_B$ to which I add the tension here and this, we will approximate it to U_J . It was this approximation, so I can easily in this mesh which is created by $V_1 = R_B I_B + U_{BE}$, since here I have a linear law, so this is Ohm's law and there is an exponential law. This exponential law, if the transistor conducts, put U_J , if the transistor blocks, well this voltage, I mean, it is not an U_J voltage it is the V_{BE} voltage.

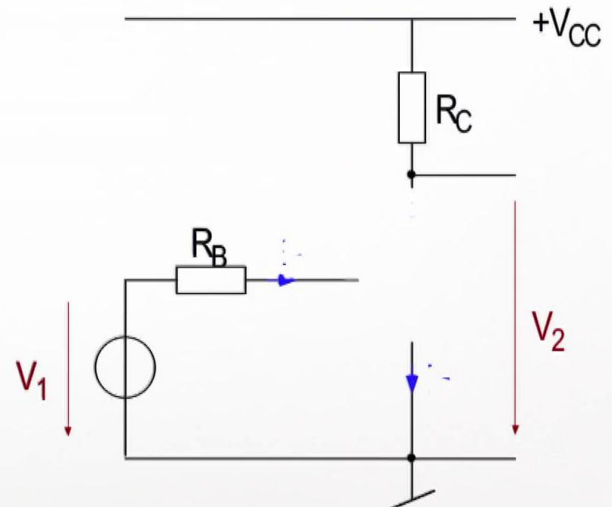
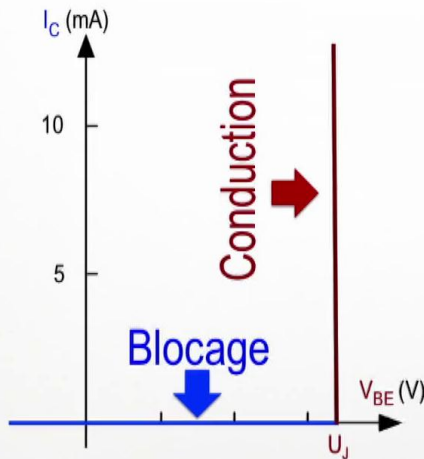
Notes

Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Blocage du transistor ($V_{BE} < U_J$):



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

But what will happen with this mesh here? We have seen that if I am here, on this law, so I have a V_{BE} voltage which is less than U_J , I'm here, it can not be an I_b , the transistor is blocked, no current flowing in either I_c or in I_e or in I_b . So voltage V_1 here is the same that I would see here. If I_b is 0, if you put $I_b = 0$, then $I_b R_b = 0$ therefore this voltage drop is equal to 0, therefore the potential difference that you see here is the same potential difference here. And that condition is achieved when your transistor does not meet a junction voltage allowing it to conduct, and that's it. If V_{be} is less than U_J , at that time, you can just remove what I noted and we will see what happens with this transistor. That is if your transistor is here, you can simply fall into the condition where the transistor is blocked and blocked mean, the model, the transistor disappear, I remove it, it's a blocked transistor. So the model of a blocked transistor is nothing at all it is... we are here, there is no I_b , there is no I_e , there is no I_c , it has just been erased. So if you put your fingers here to see the Voltage V_2 , well V_2 is nothing other than V_{CC} . And if you look V_1 , well V_1 on this side or that side is the same given the current here is 0. And like that, when we say, a transistor in a blocked state, it is simply an equivalent diagram, it is removed from the circuit.

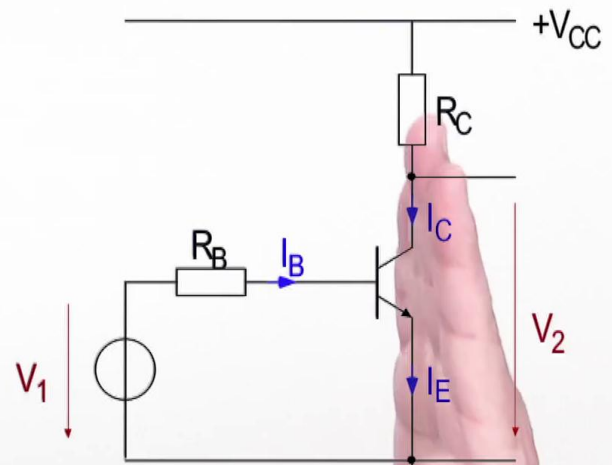
Notes

Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Fonctionnement normal ($V_{BE} \approx U_J$):



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

Therefore the blocking of the transistor when V_{be} is less than U_j , that's what I just said, $I_c = I_e = I_b = 0$. And V_1 is less than U_j , this voltage drop is zero. This voltage and this same voltage here are the same because $I_b = 0$ so this potential is equal to this potential and we said just now, and we have seen that V_2 is equal to V_{CC} because there is no current flowing thus the current that passes I_c through the R_c resistor or this voltage drop here, that's $V_{RC} = 0$. Therefore this voltage is equal to this voltage here. We will now start looking at when V_{be} is of the order of U_j . So your transistor begins to conduct. If your transistor begins to conduct, the more you raise V_1 , the more the current I_b will increase. The more you will have a current I_c that increases with more I_e which is equal to I_c , so we're looking at this transistor as if there are two mesh and that's how it should be analyzed. So if someone shows you a diagram as this, you must look at what is on this side compared to what is on the other side. That is the entrance to your transistor, this is where you control it. This is the output of your transistor where you observe the voltage V_2 which is proportional to the voltage V_{RC} , of course, because the sum of the two is equal to V_{CC} .

Notes

Summary

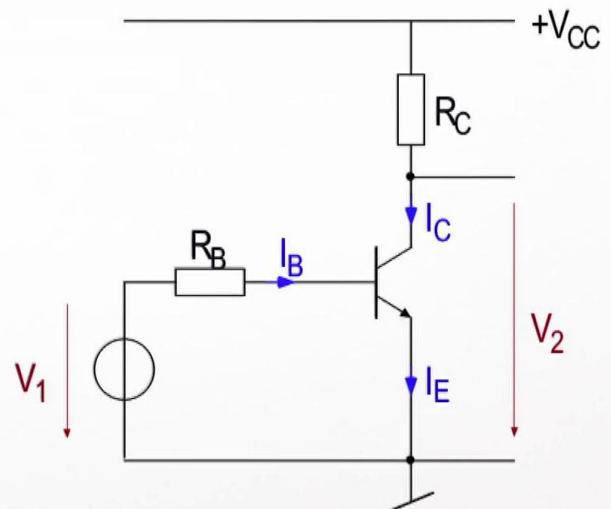


13m 48s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

So if you look at this transistor, you always start by the control junction, or by the part where we're.. we said it is an electron tap, so that's where I'll control the tap. So this is where I'll change this voltage V_{BE} for a current to begin flowing. Of course, the change in V_{be} is extremely low, it is of the order of U_J , but we are talking about changes of millivolt. This is less than U_T , and U_T is 26 millivolts, so the thermodynamic voltage of the transistor. So when we vary V_{VE} with very little variations, well we will observe the following. So when V_{be} is equal to U_J , I'll take the mesh here and I'll write V_1 equal, it is a vector, at I_B multiplied by R_B , the more I'll make this approximation, the V_{BE} order of magnitude will be of this approximation in large-signals equal to U_J . When you look at this, you will say, of course, when my transistor begins to conduct, it will have I_B . Well I_B will pass, it will generate a current I_B . So there we analyzed what happens to this side. We will again look at it in more details. This is what I just calculate, $V_1 = I_B R_B + U_J$. And there I can talk about a current I_B , and this current I_B depends on V_1 and this approximation U_J divided by R_B .

Notes

Summary

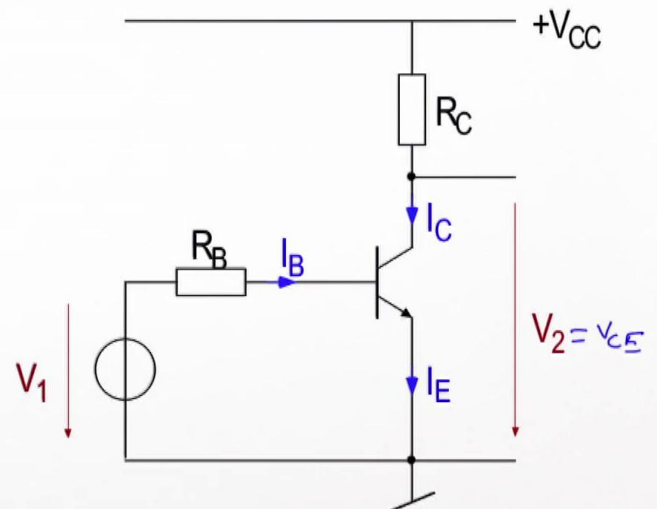


15m 21s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Fonctionnement normal ($V_{BE} \approx U_J$):

- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

Of course, the resistance R_B is extremely important. If we would not have put R_B here, we would have ended up controlling the voltage V_1 that comes directly in base-transmitter, it is impossible to do because you have an exponential variation of the current with respect to this voltage. But when we look at it here we're saying I_B is equal to the voltage V_1 minus some constant U_J . And it remains the law of ohm $R_B I_B$ that we see, so it's I_B this voltage divided by the resistor R_B . And here I can talk of this law provided that I verify that V_2 is necessarily greater than 0. If I do not check it, well I can not write this law, that means that my transistor is saturated. If I made such a calculation and I check, I can even put the numerical values I have here and see what the current going through my transistor is with respect to a given voltage. We said we analyze what is on this side and now we will analyze what is on the other side. So we looked at the control part, we will look at how the transistor output, V_2 , which is nothing other than V_{CE} . In this case, it's V_2 , it is between collector and transmitter. So this voltage here, V_2 , I only have to take the vector V_{CC} from here to here, which is equal to $I_C R_C$, so here I have $I_C R_C + V_2$.

Notes

Summary

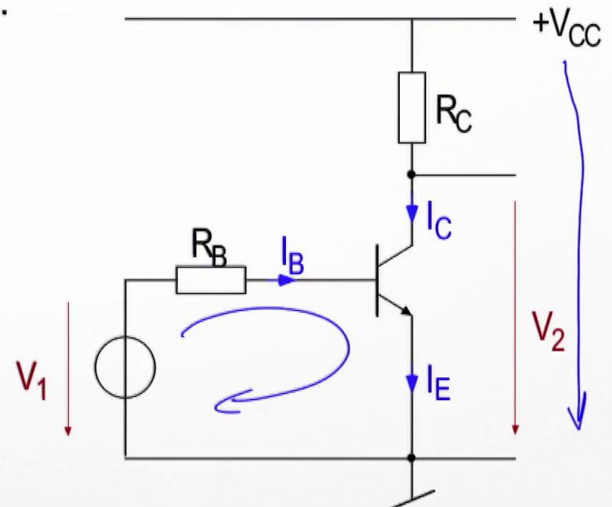


17m 08s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J, V_{CE} > 0$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$
- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

And that's what I wrote here, So $V_{CC} = I_C R_C + V_2$. In other words, $V_2 = V_{CC} - I_C R_C$. And I know that this current I_C , if my transistor is in normal mode, is proportional to $\beta \times I_B$, that's what I'm doing here, I replace it. Sure I can write, if V_2 is greater than 0, so it is in the condition that C_2 is strictly positive. And once I have that, I can replace I_B that I have just calculated, I_B was calculated in this mesh, we are bringing it back towards the exit through I_C and there, I really wrote all I can draw as Kirchhoff law that allows me to write all voltages and current in an operation mode with the output voltages in respect to the input voltage. Remember that in I_B hides V_1 and that's what I'll do now. This is what I wrote at the beginning for this mesh and for this second mesh here, I just wrote this. And we saw that the current I_B is the link between the two. This is what connects the output to the input because it will be at the output multiplied by β to give I_C and I will replace it here and I get a relationship in which I see that $V_2, f(V_1)$, which is my goal. I would like to do a transfer function in which I put a voltage V_1 and I want to see the voltage V_2 with the transistor which may be in all these modes. So I replaced this by this and I get this.

Notes

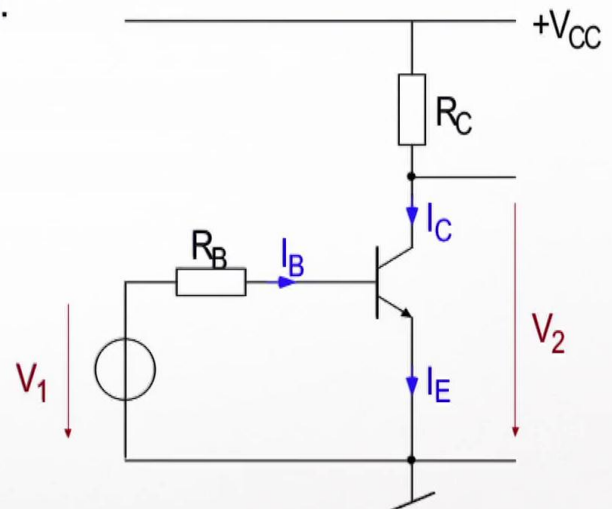
Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J, V_{CE} > 0$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$
- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$
- $V_2 = V_{CC} - \beta R_C (V_1 - U_J)/R_B$
- $V_2 = V_{CC} - 10 (V_1 - U_J) = V_{CE} > 0$
- $V_2 = V_{CC} + 10U_J - 10 V_1 = V_{CE} > 0$
- $V_1 < 1.2 V$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

So once replaced I_B in there, it gives me the relationship. I'll let you check, you're going to end up with a relationship in which you have β values, remember that it is a given transistor, So we gave a $\beta = 100$, we were given a resistance value of 10 kilohms and a collector resistor of 1 kilohm and we supply with a voltage source of 5 volts. And we get a voltage $V_2 = V_{CC} - 10 V_1 - U_J = V_2$ AVce. It is this voltage here, collector transmitter, and we would like to check what value of V_1 , or what is the limit value of V_1 for which V_2 is not equal to 0. What I'm saying is extremely important because now in reality we see, what will happen with your layout, if you write that law and you replace with the values we have here $\beta R_C R_B$ by their value, you find V_2 is equal to V_{CC} , remember that this is 5 volts, $10 \times U_J$, so it's 10×0.7 volts and $- 10 \times V_1$, it will depend on the value of V_1 . And all this will give you the Vce voltage. Obviously, if you have some V_1 that you put in here that gives you this equal to 0, it's the limit value, so VCE becomes equal to 0 if $V_1 = 1.2$. So less than 1.2, you are sure that your transistor has a strictly positive V_2 voltage.

Notes

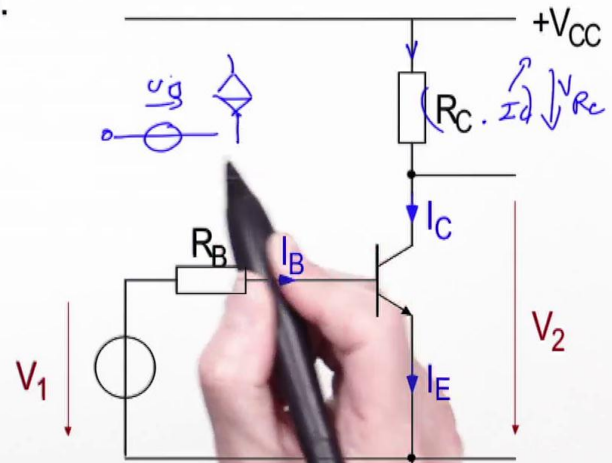
Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J, V_{CE} > 0$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$
- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$
- $V_2 = V_{CC} - \beta R_C (V_1 - U_J)/R_B$
- $V_2 = V_{CC} - 10 (V_1 - U_J) = V_{CE} > 0$
- $V_2 = V_{CC} + 10U_J - 10 V_1 = V_{CE} > 0$
- $V_1 < 1.2 V$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

If you have $V_1 = 1.2$ volts, you will get a relationship in which the voltage V_2 will be equal to 0. And who did it? It's you. Because you chose a resistor R_C which is 1 kilo ohm. You applied voltage here. If you put a vector here, you say this vector is $R_C \times I_C$ that gives you the V_{RC} voltage, know that this parameter $R_C I_C$, which is equal to V_{RC} , plus I_C increases, look at what happens with this vector. You are about to increase this current, voltage and the current in a resistor follows. Look, this voltage increases, increases, increases. During that time, the voltage V_2 drops, drops, drops, drops, until you apply on $V_2 = 0$, and you push your transistors in saturation. As long as you are with a voltage $I_C R_C$ which allows this tension not to crush the voltage V_2 so that it becomes 0, you are sure your transistor is in normal mode. So your transistor gives you a current source, here. I_C remains a source of current. It was said that if I want to replace this diagram by its earlier model, I only have to take a source voltage I call U_J . I refer you to the table that had been drawn before. We place a controlled current source, here. And this controlled current source is the source of your current.

Notes

Summary

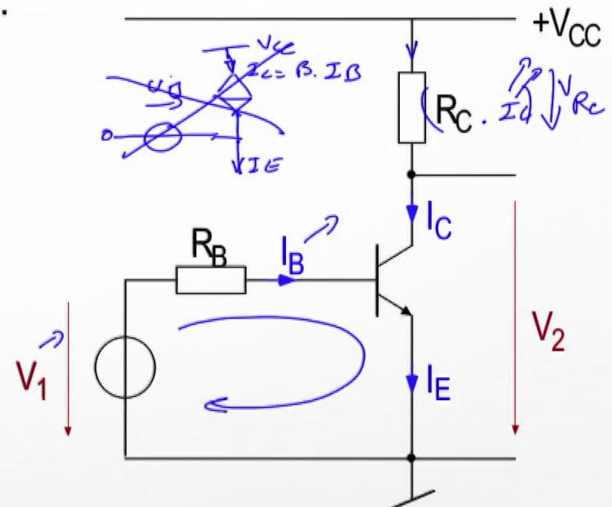


22m 28s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J, V_{CE} > 0$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$
- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$
- $V_2 = V_{CC} - \beta R_C (V_1 - U_J)/R_B$
- $V_2 = V_{CC} - 10 (V_1 - U_J) = V_{CE} > 0$
- $V_2 = V_{CC} + 10U_J - 10 V_1 = V_{CE} > 0$
- $V_1 < 1.2 V$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

Here you have I_e . And here you have a current $I_c = \beta \times I_b$. Look, if you remove this transistor and you put this in its place, you will see what happens with your circuit in normal mode. But the more you increase I_b , the more you will increase I_c , the greater the voltage drop across R_c increases. And it will push V_2 to stretch to 0. But when you have crushed, V_2 is equal to 0, know that your transistor, is no more this. You can remove it and replace it with the famous diagram that we showed too, that I will show right after. There is a short-circuit between collector-transmitter. And then if you look at what is happening in this mesh here, whenever you increase V_1 , you will increase I_b . I_c no longer follows, there is no more this relationship. So I_e will increase, of course. And as you continue to increase, I_b increases, and you are just in this mesh that will push I_b to increase, and you no longer have a transistor effect, it is replaced by a short-circuit. Therefore the saturation of a transistor is not a fact related to the transistor, it is the circuit in which you have set it, and the values of elements that impose this saturation.

Notes

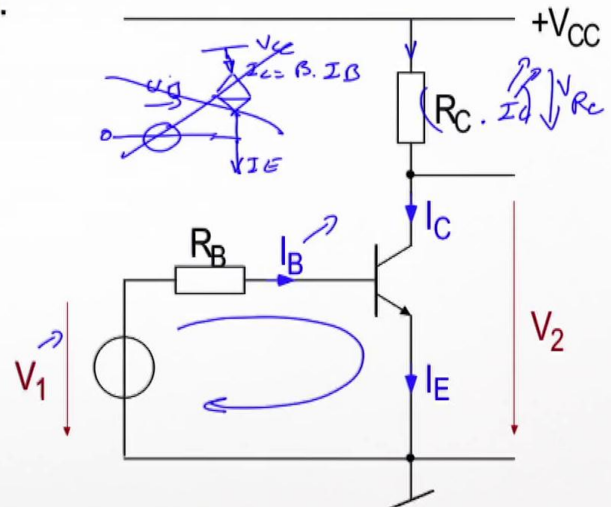
Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

• Fonctionnement normal ($V_{BE} \approx U_J, V_{CE} > 0$):

- $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B$
- $I_C = \beta I_B$
- $V_2 = V_{CC} - I_C R_C = V_{CC} - \beta I_B R_C$
- $V_2 = V_{CC} - \beta R_C (V_1 - U_J)/R_B$
- $V_2 = V_{CC} - 10 (V_1 - U_J) = V_{CE} > 0$
- $V_2 = \underbrace{V_{CC} + 10U_J}_{5 + 10 \times 0.7} - 10 V_1 = V_{CE} > 0$
- $V_1 < 1.2 V$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

I would like to draw your attention to this factor of 10, that I see here, with a minus sign in front. So if you look $V_2=f(V_1)$, what we want to get, is a DC component. This, is $5+7$. So we have here a completely DC component, it will not change, it's always like that. $-10 \times V_1$. So every time you increase V_1 , you subtract from that amount an amount $10 \times V_1$. But remember this $10 \times V_1$. Thus, V_2 is associated with 10, in absolute value, compared to V_1 , and that's what we will call later the gain of your transistor. And this is where your transistor will work as an amplifier. We will see it afterwards.

Notes

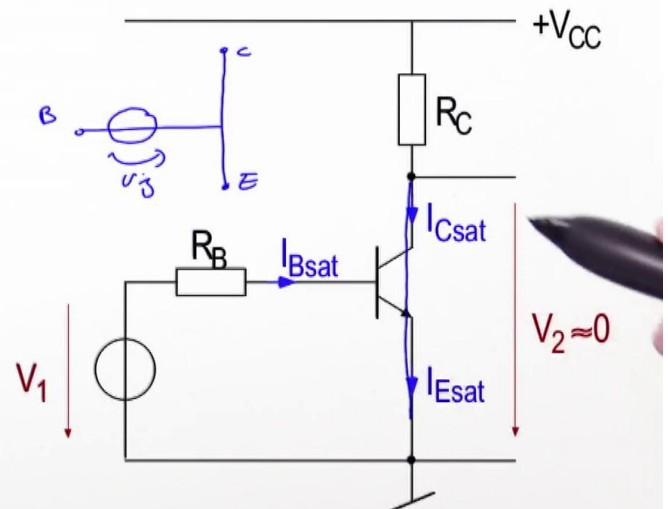
Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Transistor en saturation ($V_2=V_{CE} \approx 0$):

- $I_{Bsat} = (V_1 - U_J)/R_B$
- $I_{Csat} = (V_{CC} - V_{CEsat})/R_C \approx V_{CC}/R_C$
- $I_{Bsat} > I_{Csat}/\beta$
- $V_1 > U_J + V_{CC}R_B/\beta R_C$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

Here is your transistor. If you did what I said just now, you have increased the current such that V_2 is short-circuited by the fact that R_C has become very large. So $V_2 = 0 = V_{ce}$, your transistor is indeed saturated. And if your transistor is in saturation, what will happen in this mesh is it's no longer an I_C control mesh. You are obliged to add the concept of saturation, saturation, saturation, and you find yourself in this. You are with your saturated transistor, and there, $I_{SAT}R_B + U_J$, this, you must always remember that the U_J approximation always works, because it is the exponential that is always in the order of U_J . So you write $I_{BSAT} = (V_1 - U_J) / R_B$. And then, instead of your transistor, you take the model that was right before, and replace your transistor by a short-circuit between the collector and transmitter, and between the base and transmitter, you have a voltage U_J . So you take this, you put in the place of your transistor, and you will end up with U_J between the base-transmitter, and you write this law here. Whereas, on the other side, when you have a short-circuit between collector and transmitter, look at this transistor, it's a short-circuit here. So that $V_2 = 0$.

Notes

Summary

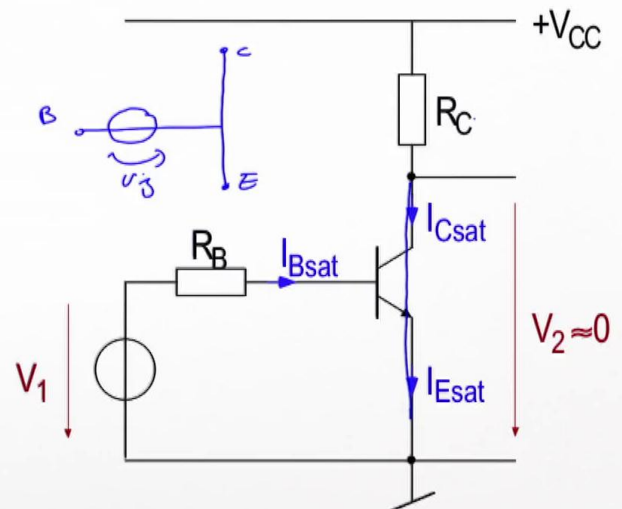


26m 23s

Exemple: Caractéristique de transfert $V_2=f(V_1)$

- Transistor en saturation ($V_2=V_{CE} \approx 0$):

- $I_{Bsat} = (V_1 - U_J)/R_B$
- $I_{Csat} = (V_{CC} - V_{CEsat})/R_C \approx V_{CC}/R_C$
- $I_{Bsat} > I_{Csat}/\beta$
- $V_1 > U_J + V_{CC}R_B/\beta R_C$



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

So there is, between V_{CC} and the ground, just the resistor R_C , which is traversed by this current I_{CSAT} . So it comes here, and we have $I_{CSAT} \times R_C = V_{CC}$. And that's what I write here. So the current I_{CSAT} , it will become constant, it can not increase. It is no longer controlled by the base current, it is equal to a constant which depends simply on the value of R_C and power supply, finally inversely proportional to R_C and the supply voltage V_{CC} . In this law, there is no more equality. And here you can make the same calculation as earlier and find that when V_1 is higher than 1.2 volts we calculated with respect to the voltage V_2 , you find $V_2 = 0$ when V_1 is greater than a voltage which is proportional to the values that we put here. And your transistor can no longer be used in an analog circuit, it is rather in a digital circuit, because it gives zero voltage beyond a certain value.

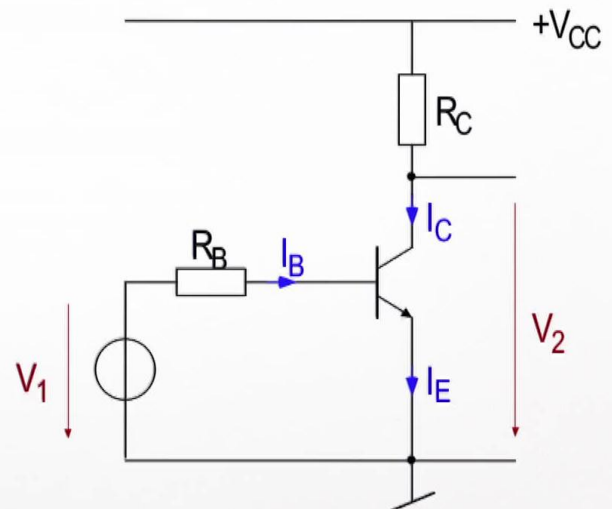
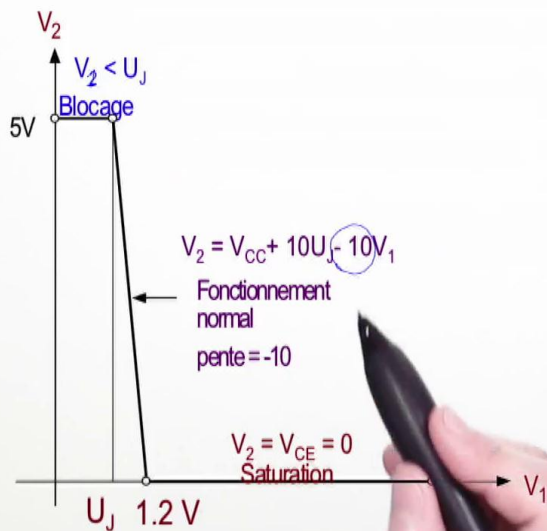
Notes

Summary



27m 59s

Exemple: Caractéristique de transfert $V_2 = f(V_1)$



Electronique II

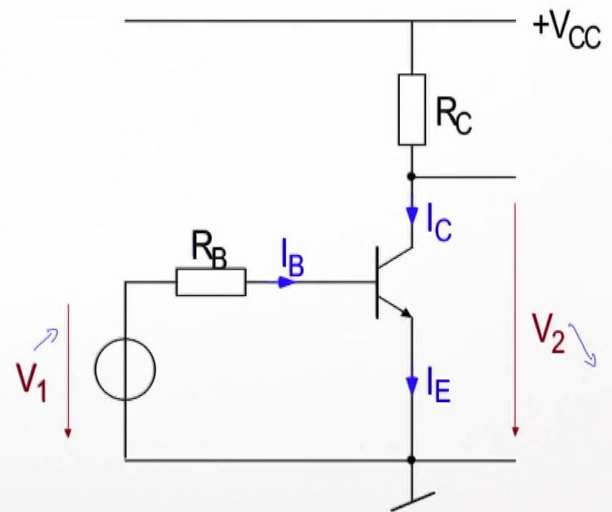
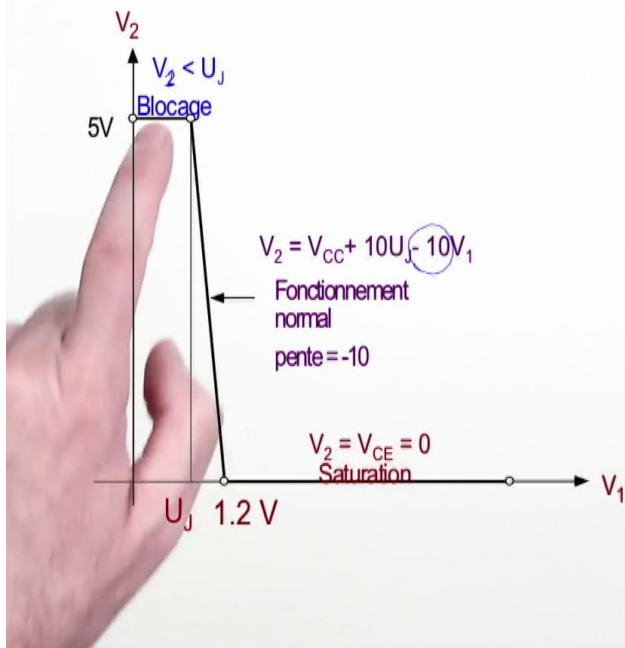
Finally, I take the same circuit, and I begin to analyze in the three cases. If the V_{be} voltage, is there, that is proportional to V_1 , so if the voltage V_{be} , there... sorry, if V_1 is less than U_j , there is no I_B current, your transistor is blocked. And we said at that time, the equivalent diagram of your transistor is really this. You remove it, that's in the case you are here. Here there is an error. It is the voltage V_1 , not the voltage V_2 . So if the voltage V_1 is lower than U_j , you end up with a model of a transistor, we remove. Then after, we will look at what will happen when one begins to make the transistor conduct. So it is here, in this part, between the blocking and saturation, there is a part here. There is a linear relationship between V_2 and V_1 , and we calculated it. The linear voltage between V_1 and V_2 , I will continue to correct the typo, that's V_1 . So when V_1 exceeds the voltage U_j , your transistor, starts to conduct, and it is in normal mode. So this is a current source. And just now, we released this expression, if you recall. And I emphasized the concept of $10 \times V_1$, with a minus sign, and it can be seen here. So you will end up with a voltage V_2 proportional to $-10 \times V_1$ plus some constant.

Notes

Summary



Exemple: Caractéristique de transfert $V_2 = f(V_1)$



Electronique II

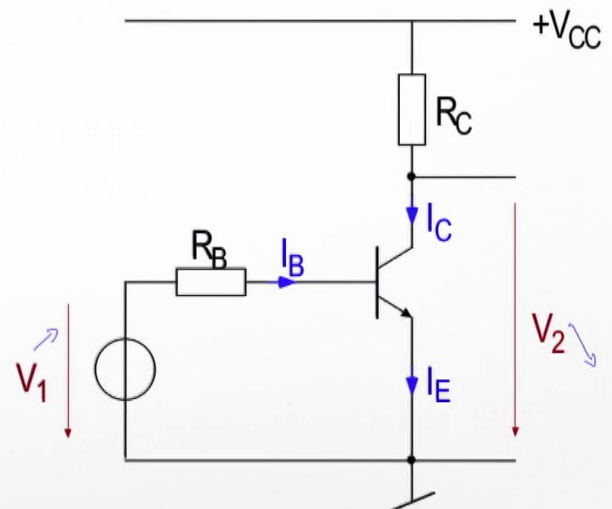
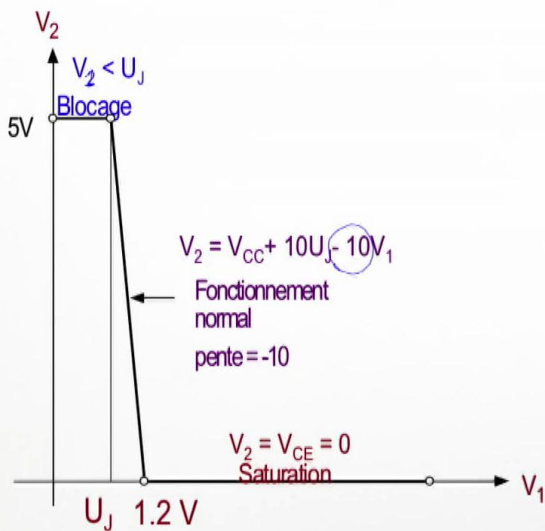
This is what makes the line you see here don't pass through the origin, because there is a DC component. Still, it has a slope that is equal to -10. Therefore the voltage V_2 with respect to V_1 , is, there is a minus sign, when one increases, the other decreases. And it multiplies the voltage $V_2 = 10 \times V_1$. It's awesome. We made an amp. So what you put here, you find it 10 times, multiplied by what is in this diagram, at the output V_2 . And you find it reversed. So if there is a sinusoidal voltage, there will be a 180° phase shift which is due to the minus sign. Now, when you arrive, you continue to increase V_1 . Then, the voltage V_2 decreases, there is the minus sign. The voltage across R_C increases until you get a voltage in which $V_2 = 0$. So your transistor is short-circuited. If it is shorted-circuited, $V_2 = 0$, we are here, and your transistor is saturated. And when your transistor is saturated, here we can no longer bind I_C to I_B because I_C is proportional to a value $I_C \times R_C = V_{CC}$. This is what we just saw. I would like to take the time and insist on the three modes seen here. Blocking, the so-called analog part of operation, wherein we had an amplifier, wherein the output voltage is multiplied by a constant which depends on the R_C and R_B values, which multiplies voltage V_1 .

Notes

Summary



Exemple: Caractéristique de transfert $V_2=f(V_1)$



Electronique II

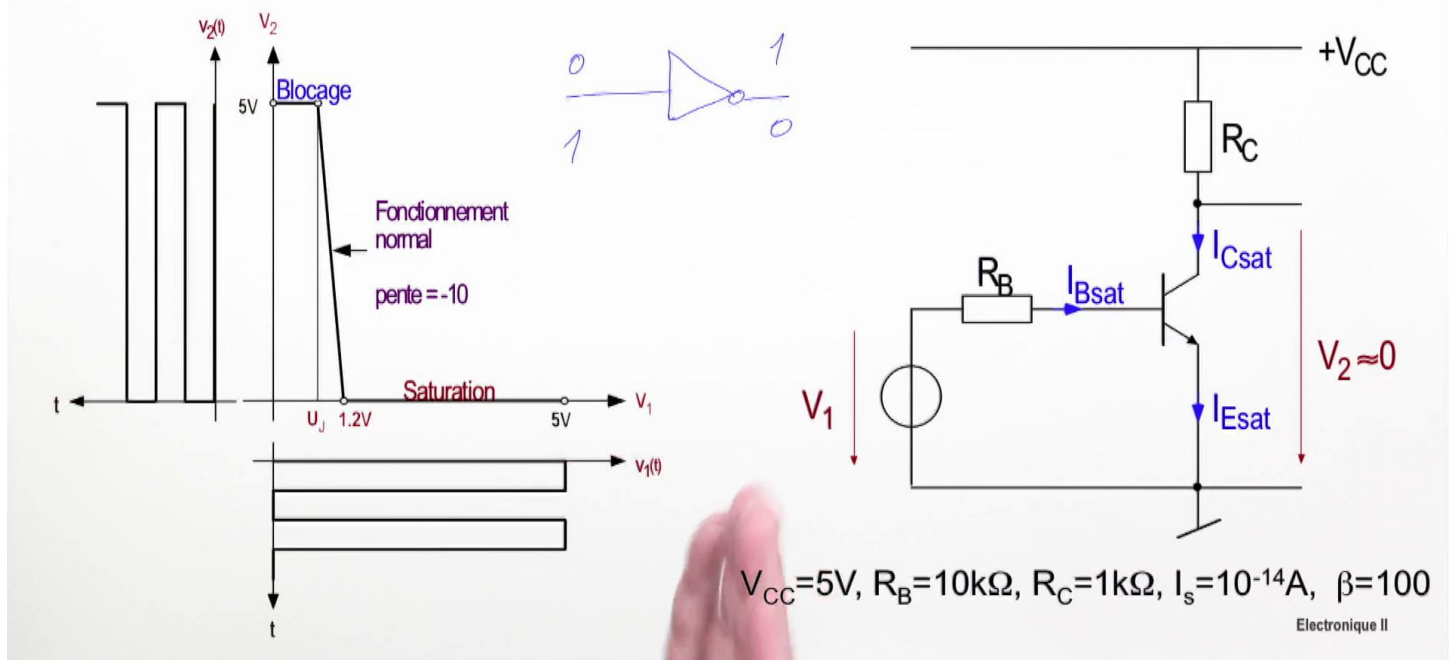
This is where we will use the transistor as an amplifier, and later we have the transistor that is saturated. So when I see this diagram here, and I want to talk about a transistor that is used as an amplifier, that we will see all along the course, later, always check that your transistor is not blocked or saturated. If you remember these two words, you say: "If my transistor is neither blocked nor saturated, my transistor is in normal operation ", and it corresponds to its use as an amplifier, with the amplifier diagrams we will study later.

Notes

Summary



Inverseur logique



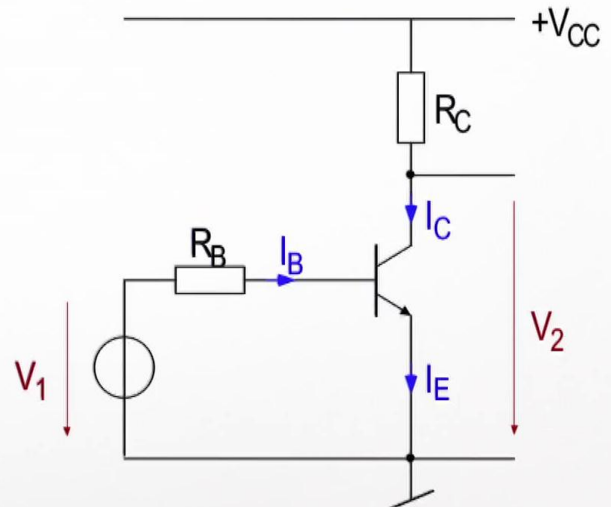
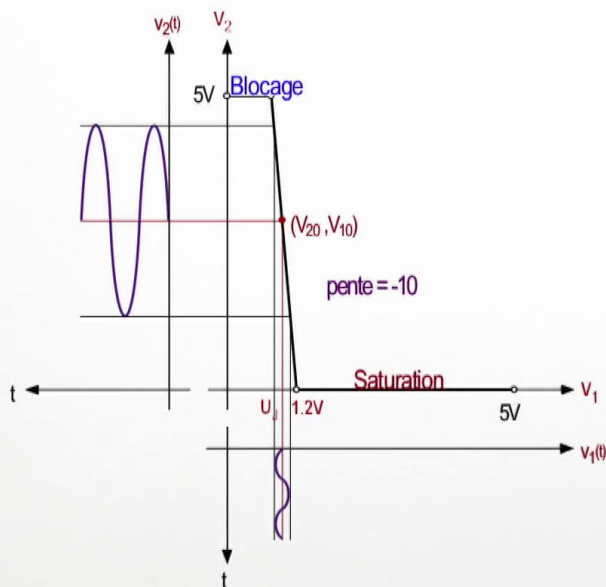
However if your transistor is blocked or saturated, your transistor is used, simply as a digital circuit, and it acts as an inverter. If you inject a voltage V_1 , a binary signal, which oscillates between 1 and 0, you will see a voltage V_2 which is also binary. It is as if you had done a logic inverter set-up, which is like this. And what you put in binary state, you find the opposite state, so a 0 gives us a 1 and 1 gives us a 0. And that's it, it's the behavior of your transistor, when you are in the blocked or saturated state.

Notes

Summary



Amplificateur de tension



$$V_{CC}=5V, R_B=10k\Omega, R_C=1k\Omega, I_s=10^{-14}A, \beta=100$$

Electronique II

If you want to use your transistor, if your transistor is in normal mode, there you go to put very low voltage variations on V_1 , it is less than the thermodynamic voltage 26 millivolts, and since there is a slope, you will find the linear output voltage, which is the voltage V_2 , which transforms the variation V_1 into a variation V_2 , which is 10 times higher, because we have a multiplication factor equal to 10. But then that's where we see the need to polarize the transistor. One of the things that will be discussed in great lengths, is that if we want to have a signal whose dynamic or whose variation is within a certain range, it is necessary to impose to this transistor a direct current and voltage. So there will be a current through the IC0 for an IB0 current, and then there will be a voltage V10, which will allow it to be in a range that all small variations imposed here turns into a variation found in the output. And we now talk of a voltage amplifier. And this is an amp that has a gain.

Notes

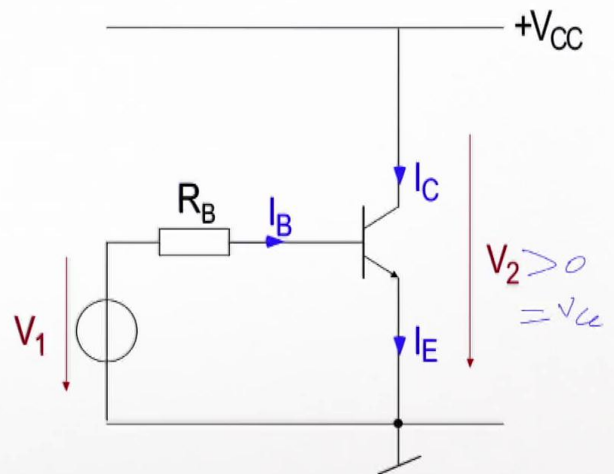
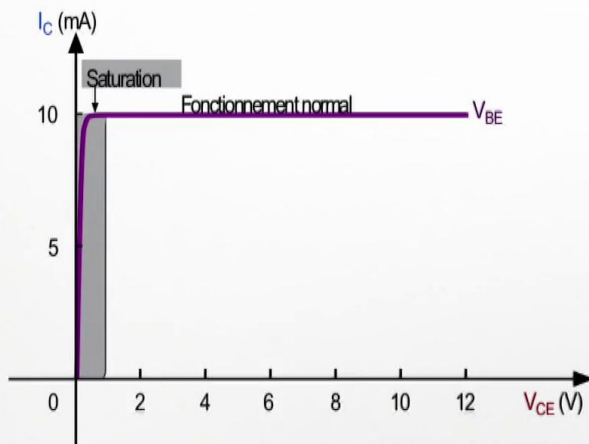
Summary



Exemple : régime de fonctionnement

- Ce transistor est en régime de fonctionnement normal

- $V_{CE} = V_2 = V_{CC} = 10V$



Electronique II

To conclude and summarize what we just saw, and really set the idea on what is an operating system of a transistor, I want to take again the diagram. In this diagram, I don't have, but the resistor R_C , I took the transistor and I put it between the supply voltage and ground. It's of no use. Do you understand that if I pull the current from V_{CC} and send it back into the current in the ground, generally, reading current is very difficult? It is read through a voltage, by Ohm's law. So I have to put it in the resistance to be able to see it. But if you take this diagram and you say: "I applied a voltage V_1 ". Let me give you an example: I put V_1 is equal to perhaps 650 millivolts, something of this magnitude, and I see that there is an I_B current that will pass, therefore, this junction is of the order of 0.6 to 0.7 volts. Then I will have a current flowing. Does $V_2 = 0$? No way. V_2 , in this case, is always equal to V_{CC} . So this is a transistor that is at all times in normal state. It can, in no case, be saturated. Why ? Because the voltage V_2 is constant and strictly positive, and equal to V_{CC} . So this is just to show that if you have a transistor, and you plug it like this, so you have a transistor that is useless, because we can not read the variation of the current.

Notes

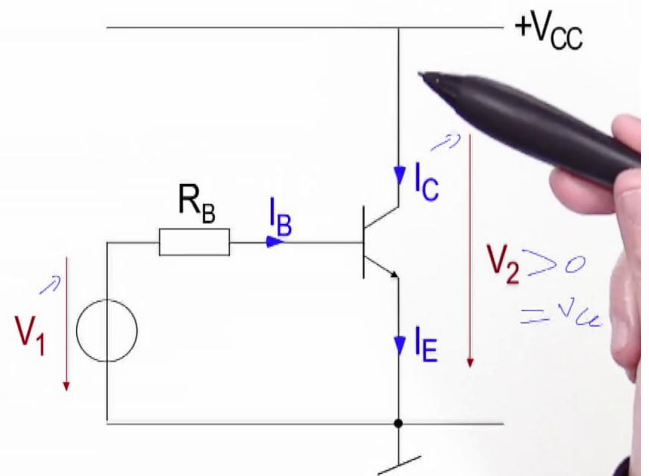
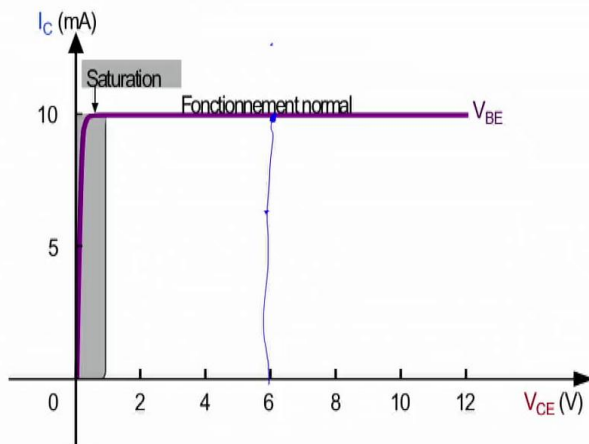
Summary



Exemple : régime de fonctionnement

- Ce transistor est en régime de fonctionnement normal

- $V_{CE} = V_2 = V_{CC} = 10V$



Electronique II

I can increase V_1 so I increases I_C , but I have not converted I_C into Ohm's law to read it in the form of voltage. So I have a current that increases, but I can not observe it. Now I'll take the same diagram. But before moving on something, so I am all the time here, I took $V_2 = V_{CC}$, and if we say V_{CC} equal to 6 volts, so I'm here somewhere. So this is a current increases. Now if you increase V_1 , you increase V_{BE} , then you're going to have this decreasing curve. And you are all the time with a single point, so you will change the current I_C . So if I increase V_1 , I'll raise the current I_C . And if I drop V_1 , I'll lower the current I_C . So I only observe current variation, provided that I check it with an ammeter. I repeat the same thing, and I'll just add a resistance here.

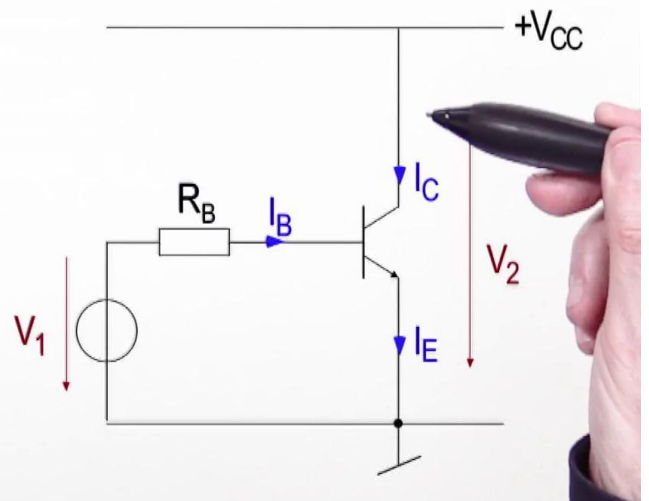
Notes

Summary



Exemple : régime de fonctionnement

- Ce transistor est en régime de fonctionnement normal
 - $V_{CE}=V_2=V_{CC}=10V$
 - Avec : $V_{CC}=10V$, $V_1=3V$, $R_B=1M\Omega$, $I_s=10^{-14}A$ et $\beta=200$
 - $V_1=I_B R_B+U_J \rightarrow I_B=(V_1-U_J)/R_B$
 - $I_B=2.3 \mu A$ et $I_C=\beta I_B=0.46 mA \approx I_E$



Electronique

So I take this transistor, and I will, if I calculate it like this without adding to it a resistance, by taking the numerical values that are here, I will end up with a current I_B which will give me a current $I_C = I_E$. Regarding the digital application I have put with the values given here, I think the base current for a transistor which has a $\beta = 200$ is of the order of 2.3 microamps, to give me a current 200 times greater, thus equal to 0.46 milliampere. But it's of no use to me, because I could not read the current. I will add a resistor here.

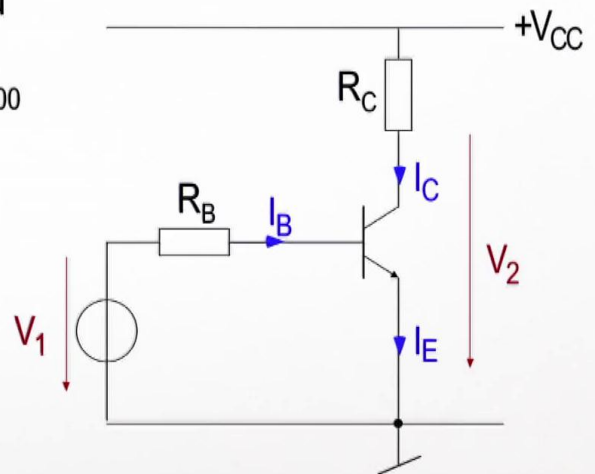
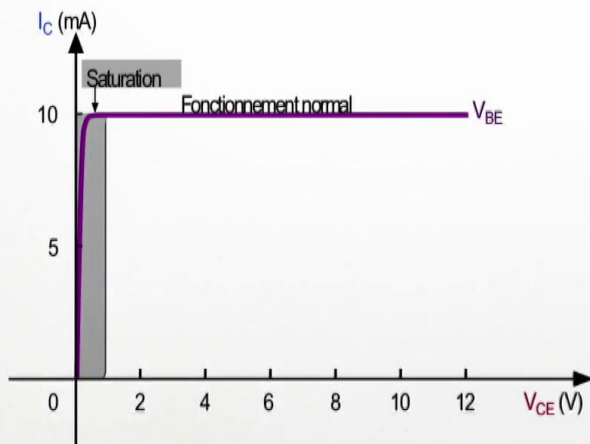
Notes

Summary



Exemple : régime de fonctionnement

- Ce transistor peut être en mode normal ou saturé en fonction de la valeur de R_C
- Avec : $V_{CC}=5V$, $V_1=3V$, $R_B=10k\Omega$, $R_C=10k\Omega$, $I_s=10^{-14}A$ et $\beta=200$



Electronique II

When I add a resistor here, it changes the data. Now, current I_C has not changed.

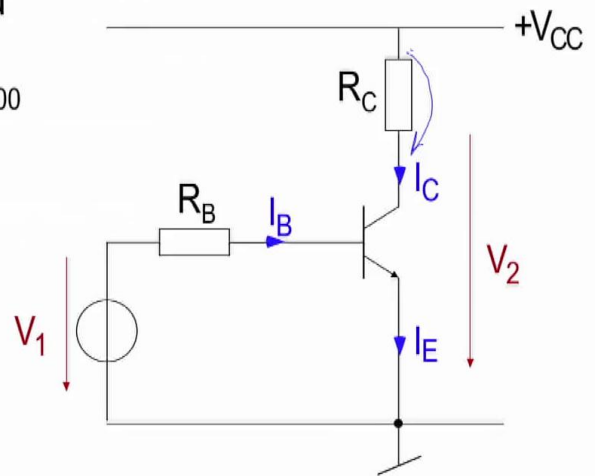
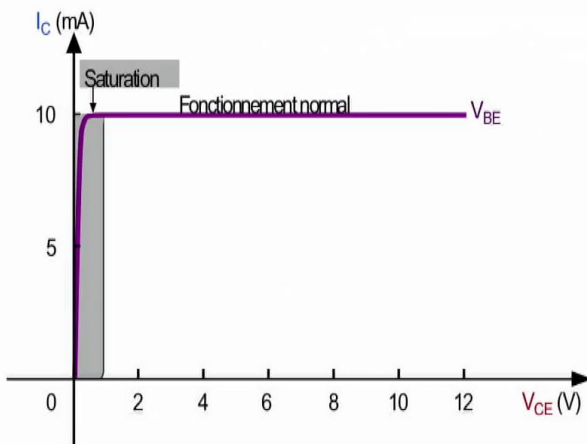
Notes

Summary



Exemple : régime de fonctionnement

- Ce transistor peut être en mode normal ou saturé en fonction de la valeur de R_C
- Avec : $V_{CC}=5V$, $V_1=3V$, $R_B=10k\Omega$, $R_C=10k\Omega$, $I_s=10^{-14}A$ et $\beta=200$



Electronique II

I go back, I have a current $I_C = 0.46$ and now I converted this current in a resistor which I inserted here. And this resistor, will convert this current into voltage at its terminals which is equal $I_C \times R_C$. This I can read. This I can well take and even inject into another transistor stage here. But it changes the data. Is this tension very big to be of the order of magnitude of V_{CC} , which cancels V_2 ? And it saturates my transistor. Or it is small and it puts the transistor in the linear region? And that is something extremely important, so it's me who decided the resistor R_C value, which I inserted, and it is my decision that $R_C \times I_C$ will have some value. And there, in that case, we can take that same set-up and make the same calculation as earlier.

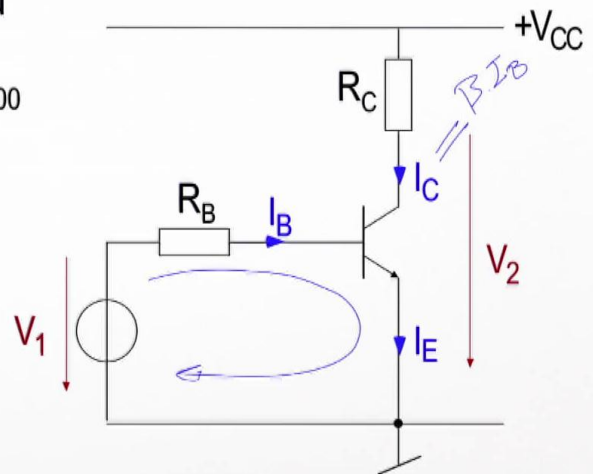
Notes

Summary



Exemple : régime de fonctionnement

- Ce transistor peut être en mode normal ou saturé en fonction de la valeur de R_C
 - Avec : $V_{CC}=5V$, $V_1=3V$, $R_B=10k\Omega$, $R_C=10k\Omega$, $I_s=10^{-14}A$ et $\beta=200$
 - $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B = 230 \mu A$
 - On suppose que $I_C = \beta I_B = 23mA$
 - $V_2 = V_{CC} - I_C R_C = 5V - 230V = -225V!!!$ Donc $V_2 = V_{CE} = 0$
 - $I_{Csat} = (V_{CC} - V_{CEsat})/R_C \approx V_{CC}/R_C = 0.5mA$
 - $I_{Esat} = I_{Csat} + I_{Bsat} = 0.5 + 0.23 = 0.73 mA$



Electronique II

I took a resistor R_C and I put 10 kilo ohms. There, this side, I have not changed anything. You remember, we said, we reason always on this side and that side. I take that side and I write the famous law of the mesh that is here: $I_B R_B + U_J = V_1$, which is written here. And I extract the value I_B . And I chose a value of R_B : 10 kilo ohms. What will give me, in this case, 230 microamps. So I have 230 microamps that will circulate here. If this set-up was in normal mode, I_C should have been equal to $\beta \times 230$ microamps here. So times I_B . So that will give me a current I_C , that I just have to calculate with the β which is equal to 200 in the example, it will give me 23 milliamps. I imposed myself 23 milliamps here. 23 milliamps which will circulate in a resistor, I gave a value of 10 kilo. If I take 23 milliamps, I put in a a resistance of 10 kilohms, the Ohm's law says 23×10 kilohms they will lead you to a voltage drop, or rather you write this mesh from here to here, you say $V_{CC} = R_C I_C + V_2$. Or you put $V_2 = V_{CC} - R_C I_C$, and you write that 23 milliamps, which multiplies the resistance of 10 kilohms here, and you're going to get a voltage drop on $V_2 = -225$ volts. So it's impossible.

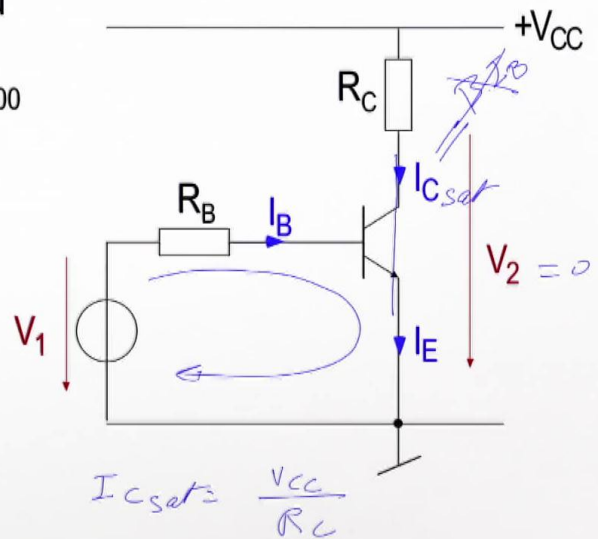
Notes

Summary



Exemple : régime de fonctionnement

- Ce transistor peut être en mode normal ou saturé en fonction de la valeur de R_C
 - Avec : $V_{CC}=5V$, $V_1=3V$, $R_B=10k\Omega$, $R_C=10k\Omega$, $I_s=10^{-14}A$ et $\beta=200$
 - $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B = 230 \mu A$
 - On suppose que $I_C = \beta I_B = 23mA$
 - $V_2 = V_{CC} - I_C R_C = 5V - 230V = -225V!!!$ Donc $V_2 = V_{CE} = 0$
 - $I_{Csat} = (V_{CC} - V_{CEsat})/R_C \approx V_{CC}/R_C = 0.5mA$
 - $I_{Esat} = I_{Csat} + I_{Bsat} = 0.5 + 0.23 = 0.73 mA$



Electronique II

When you feed a transistor with 5 volts, there is a supposition we just made, which is not correct, that is to say βI_B is valid. Why ? Because I have found that by feeding 5 volts $V_2 = -225$ volts, so it's not possible. So there is an assumption that I just did which is not correct: this is $I_C = \beta \times I_B$. Why ? Because when I added that R_C and this R_C , by a current going through, imposed $V_2 = 0$, you remember that this voltage drop is very large, and it saturated the transistor. So in reality, $V_2 = V_{CE} = 0$. So that law is not at all correct, in this example here. So you will end up with something else instead, you'll say I_{CSAT} is limited. The current here can never reach the value I calculated here, it is certainly lower. Why ? Because the maximum value of this current is when the transistor saturates. So here, I have a short-circuit, and I can write at this point, $V_2 = 0$ and $I_{CSAT} \times R_C$ can not be equal to V_{CC} . And that's the maximum I can get. So it will give me a I_{CSAT} current that will be a constant equal to V_{CC}/R_C . And this is the maximum current that I can have. And when I get to this current here, it stabilizes here.

Notes

Summary



40m 56s

Résumé des modes de fonctionnement



Electronique II

The transistor is no longer a current source, and the transistor will act in saturated mode, and I can continue to increase I_B , but it has no impact on the output. So I find a current of 0.5 milliamps, so I am far from these 23 milliamps I assumed to be, if the transistor had not been saturated. Then that is right. And now, if I want to calculate I_B , I have no right divide I_{CSAT} by β . I have to take the mesh that is here, and say what is the value of I_B . Beside, it was calculated, it is there. And it is sure that I_E is equal to the sum of this and this, that will give I_E . It is not at all equal to I_{CSAT} . I hope that with that example, you managed to understand that it is the values you give yourself that can saturate a transistor or bring your transistor to operate in normal mode, or block it. It's you who decide it, based on these different values of resistance you have chosen. This week, we saw all modes of transistor operation, we studied in details the different electrical characteristics of the transistor, and we drew useful conclusions as introduction, to show that a transistor, of course, has modes of operation which are mainly dependent on the circuits in which we will put them.

Notes

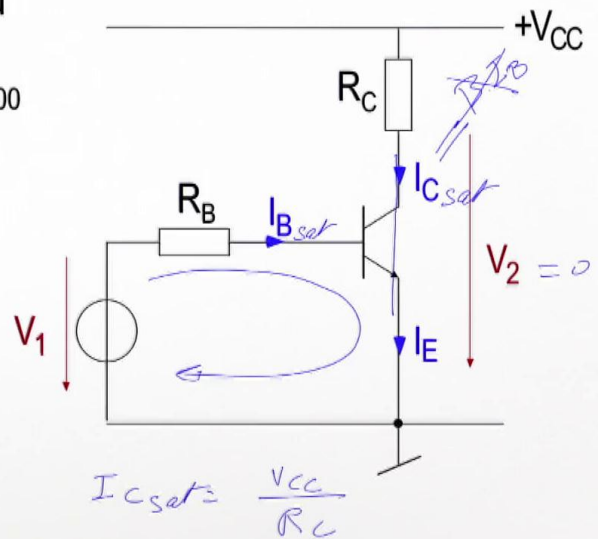
Summary



42m 24s

Exemple : régime de fonctionnement

- Ce transistor peut être en mode normal ou saturé en fonction de la valeur de R_C
 - Avec : $V_{CC}=5V$, $V_1=3V$, $R_B=10k\Omega$, $R_C=10k\Omega$, $I_s=10^{-14}A$ et $\beta=200$
 - $V_1 = I_B R_B + U_J \rightarrow I_B = (V_1 - U_J)/R_B = 230 \mu A$
 - On suppose que $I_C = \beta I_B = 23mA$
 - $V_2 = V_{CC} - I_C R_C = 5V - 230V = -225V!!!$ Donc $V_2 = V_{CE} = 0$
 - $I_{Csat} = (V_{CC} - V_{CEsat})/R_C \approx V_{CC}/R_C = 0.5mA$ ✓
 - $I_{Esat} = I_{Csat} + I_{Bsat} = 0.5 + 0.23 = 0.73 mA$



Electronique II

And this is especially the calculations of elements and components that we will put around that will allow us to make electrical diagrams that hold. Either you want to use it in analog mode and we made an amp, and must polarize, and it will have a gain, and it is a linear gain. Either we use it in the blocked or saturated mode and there, it would be useful to make an open or closed switch, so useful for logic circuits.

Notes

Summary



43m 52s